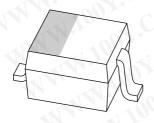
DISCRETE SEMICONDUCTORS

DATA SHEET

勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-34970699 胜特力电子(深圳) 86-755-83298787



PMEG2010EALow V_F (MEGA) Schottky barrier diode

Product data sheet Supersedes data of 2002 Dec 10



Low V_F (MEGA) Schottky barrier diode

PMEG2010EA

FEATURES

Forward current: 1 AReverse voltage: 20 V

Ultra high-speed switching

· Very low forward voltage

· Very small plastic SMD package.

APPLICATIONS

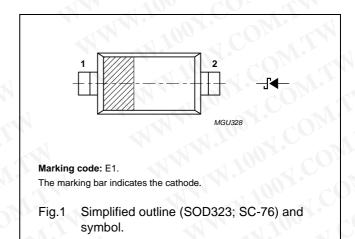
- Ultra high-speed switching
- Voltage clamping
- Protection circuits.

DESCRIPTION

Planar Maximum Efficiency General Application (MEGA) Schottky barrier diode with an integrated guard ring for stress protection, encapsulated in a SOD323 (SC-76) very small SMD plastic package.

PINNING

PIN	DESCRIPTION		
1 100	cathode		
2	anode		



ORDERING INFORMATION

TYPE	PACKAGE		
NUMBER	NAME	DESCRIPTION	VERSION
PMEG2010EA	_	plastic surface mounted package; 2 leads	SOD323

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_R	continuous reverse voltage		-	20	V
I _F	continuous forward current	100, 50	-	1	Α
I _{FSM}	non-repetitive peak forward current	t _p = 8.3 ms half sinewave; JEDEC method		5	А
T _{stg}	storage temperature	1001	-65	+150	°C
Tj	junction temperature	W. W.	_	125	°C
T _{amb}	operating ambient temperature	100	-65	+125	°C

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Low V_F (MEGA) Schottky barrier diode

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CHARACTERISTICS

T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _F	continuous forward voltage se	e Fig.2; note 1			
	100 x COM LAN	I _F = 10 mA	240	270	mV
	N. O. O. O.	I _F = 100 mA	300	350	mV
	1700 T CO 171	I _F = 1000 mA	480	550	mV
I _R	continuous reverse current se	e Fig.3; note 1	100,2		
M.M.W.100	TH. TO THE STATE OF	V _R = 5 V	5	10	μΑ
	14 100 COR 11/1	V _R = 8 V	7	20	μΑ
	111 N. 1001. O.M.	V _R = 15 V	10	50	μΑ
C _d	diode capacitance V _R	e = 5 V; f = 1 MHz; see Fig.4	19	25	pF

Note

1. Pulsed test: $t_p = 300 \ \mu s; \ \delta = 0.02.$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	220	K/W
		note 2	180	K/W

Notes

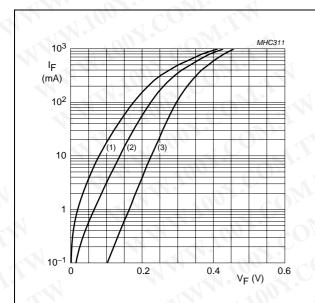
- 1. Device mounted on an FR4 printed-circuit board with Cu clad 10 x 10 mm.
- 2. Device mounted on an FR4 printed-circuit board with Cu clad 40 x 40 mm.

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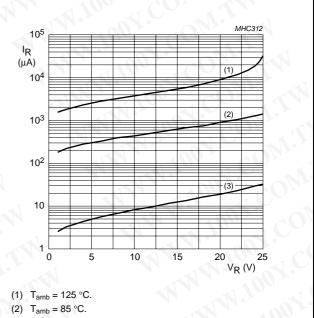
PMEG2010EA

GRAPHICAL DATA



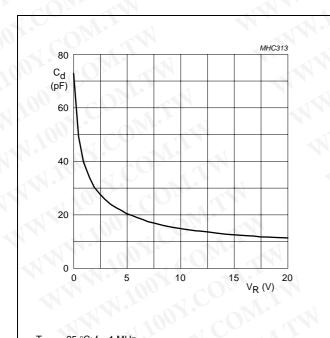
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.2 Forward current as a function of forward voltage; typical values.



(3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.3 Reverse current as a function of reverse voltage; typical values.



 T_{amb} = 25 °C; f = 1 MHz.

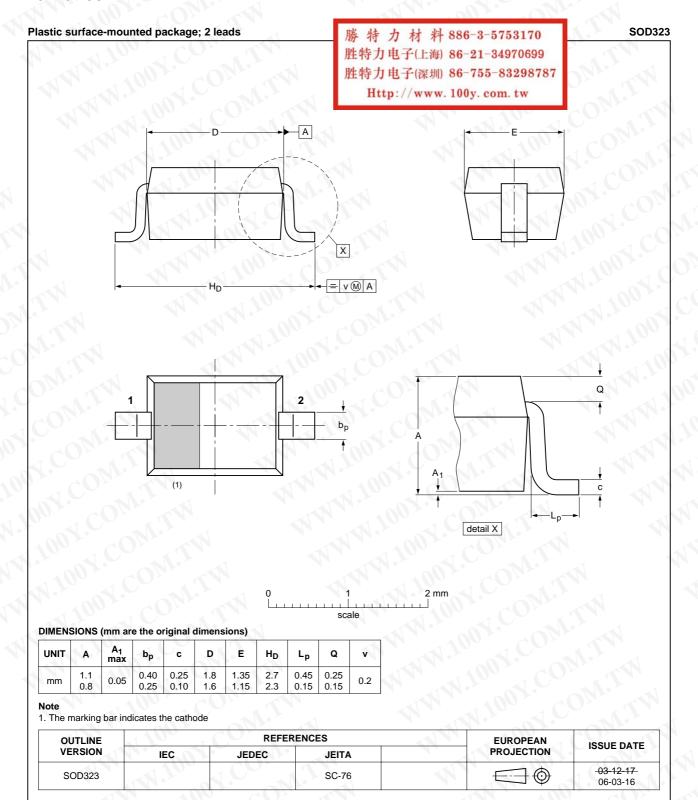
Fig.4 Diode capacitance as a function of reverse voltage; typical values.

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PACKAGE OUTLINE



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Product data sheet

Low V_F (MEGA) Schottky barrier diode

PMEG2010EA

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- Please consult the most recently issued document before initiating or completing a design.
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

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Printed in The Netherlands R76/02/pp7 Date of release: 2004 Feb 06 Document order number: 9397 750 12626

